

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

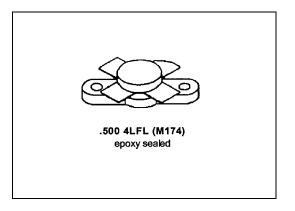
PHONE: (215) 631-9840 FAX: (215) 631-9855

MS1051

RF & MICROWAVE TRANSISTORS HF SSB APLICATIONS

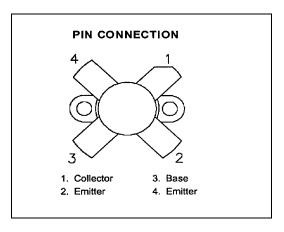
Features

- 30 MHz
- 12.5 VOLTS
- P_{OUT} = 100 WATTS
- G_{PE} = 12.0 dB MINIMUM
- IMD = −30 dBc
- GOLD METALLIZATION
- COMMON EMITTER CONFIGURATION



DESCRIPTION:

The MS1051 is a 12.5 V Class C epitaxial silicon NPN planar transistor designed primarily for HF communications. This device utilizes state-of-the-art diffused emitter ballasting to achieve extreme ruggedness under severe operating conditions.



ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

| Symbol | Parameter | Value | Unit |
|-------------------------|---------------------------|-------------|------|
| \mathbf{V}_{CBO} | Collector-Base Voltage | 36 | V |
| V _{CEO} | Collector-Emitter Voltage | 18 | V |
| V _{EBO} | Emitter-Base Voltage | 4.0 | V |
| I _C | Device Current | 20 | Α |
| P _{DISS} | Power Dissipation | 290 | W |
| T _J | Junction Temperature | +200 | °C |
| T _{STG} | Storage TEmperature | -65 to +150 | °C |

THFRMAI DATA

| R _{TH(J-C)} | Thermal Resistance Junction-case | 0.6 | °C/W | | | | | |
|----------------------|----------------------------------|-----|------|--|--|--|--|--|



MS1051

ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

STATIC

| Symbol | Test Conditions | | | Value | | |
|--------------------------|------------------------|----------------------|------|-------|------|------|
| | | | Min. | Typ. | Max. | Unit |
| BV _{CBO} | I _C = 100mA | I _E = 0mA | 36 | | | ٧ |
| BV _{CES} | I _C = 100mA | $V_{BE} = 0V$ | 36 | | | V |
| BV _{CEO} | I _C = 10mA | $I_B = 0mA$ | 18 | | | V |
| BV _{EBO} | I _E = 20mA | $I_C = 0mA$ | 4.0 | | | V |
| I _{CES} | V _{CE} = 15V | $I_C = 0mA$ | | | 20 | mA |
| \mathbf{h}_{FE} | $V_{CE} = 5V$ | $I_C = 5A$ | 20 | | 200 | |

DYNAMIC

| Symbol | Test Conditions | | | Value | | | |
|--------------------|--|--------------------------|-------------------------|-------|------|------|------|
| | | | | Min. | Typ. | Max. | Unit |
| \mathbf{P}_{OUT} | f = 30 MHz | V_{CE} = 12.5 V | I _{CQ} = 150mA | 100 | | | W |
| G _P | f = 30 MHz | V _{CE} = 12.5 V | I _{CQ} = 150mA | 11 | 13 | | dB |
| IMD ₃ * | P _{OUT} = 100 W PEP | V _{CE} = 12.5 V | I _{CQ} = 150mA | | | -30 | dBc |
| C _{OB} | f = 1 MHz | V _{CB} = 12.5 V | | | 400 | | pf |
| Condition | f1 = 30.000MHz | f2 = 30.001MHz | | | | | |



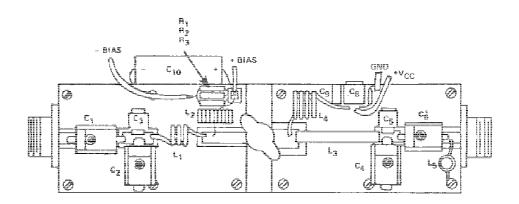
MS1051

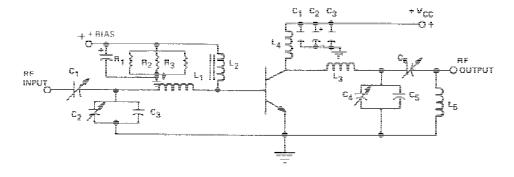
IMPEDANCE DATA

| FREQ | $\mathbf{Z}_{IN}(\Omega)$ | $\mathbf{Z}_{CL}(\Omega)$ | | |
|--------|---------------------------|---------------------------|--|--|
| 30 MHz | 0.57 + j 0.78 | 0.80 + j 0.43 | | |

 $P_{OUT} = 100 \text{ WPEP}, V_{CE} = 12.5 \text{ V}$

TEST CIRCUIT





9 - 180pF Arco 463 C2 5 - 380pF Arco 465 C3 200pF Arco 465 C4, C6: 170pF Arco 469

C7 0.1μF Ceramic Disc C5, C8: 1000pF Unelco 10μF Electrolytic, 35Vdc 1000μF Electrolytic, 35Vdc C9

C10 L1 2 1/2 Turns, #14 AWG, I.D. Loose Wound

16 Turns, #16 AWG, Enameled Wire on Micrometals Torroid #T-94 L2

Copper Strap 1/4" Widht, Length 1 1/2,

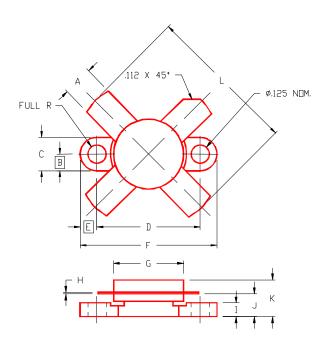
Height 1/2"
4 Turns, #16 AWG, Enameled Wire 3/8" I.D.
5 Turns, #18 AWG on 1/4" I.D. Coil Form
Length 1/2", Ferrite Slug

R1, R2, R3 : 1.5 Ohm, 1 Watt Carbon



MS1051

PACKAGE MECHANICAL DATA



PACKAGE STYLE M174

| | | MIN1MUM | MAXIMUM | П | | MUM[N]M | MAX]MUM |
|--|---|------------|------------|---|---|-----------|-------------|
| | | INCHE2/MM | INCHES/MM | | | INCHES/MM | INCHES/MM |
| | Α | .220/5,59 | .230/5,84 | П | I | .090/2,29 | .110/2,79 |
| | В | .125/3,18 | | | J | .160/4,06 | .175/4,45 |
| | С | .245/6,22 | .255/6,48 | П | К | | .280/7,11 |
| | D | .720/18,28 | .730/18,54 | | L | | 1.050/26,67 |
| | Ε | .125/3,18 | | | | | |
| | F | .970/24,64 | .980/24,89 | П | | | |
| | G | .495/12,57 | .505/12,83 | П | | | |
| | Н | .003/0,08 | .007/0,18 | | | | |